

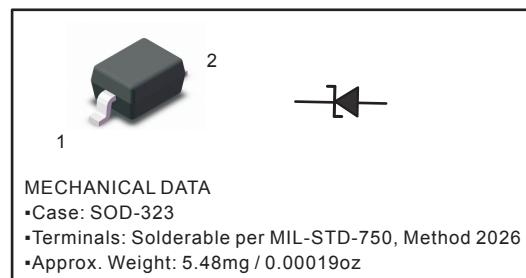
## Transient Voltage Suppressors for ESD Protection

### General Description

The ESD3Z5V0 Series is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode

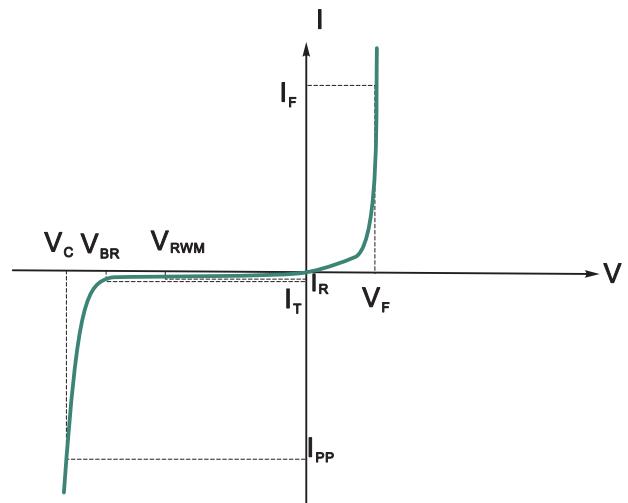


### Features

- Small Body Outline Dimensions
- 350 Watts peak pulse power ( $t_p = 8/20\mu s$ )
- Transient protection for data lines to
- IEC 61000-4-2 (ESD)  $\pm 15kV$  (air),  $\pm 8kV$  (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 24A (8/20 $\mu s$ )
- Small package for use in portable electronics
- Suitable replacement for MLV's in ESD protection applications
- Protects one I/O or power line
- Low clamping voltage
- Notebooks, Desktops, and Servers
- Portable Instrumentation Pagers Peripherals
- Working voltages: 5V and 12V
- Low leakage current
- Solid-state silicon-avalanche technology
- We declare that the material of product compliance with RoHS requirements.
- S-Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

### Electronics Parameter

Parameter	Symbol
Maximum Reverse Peak Pulse Current	$I_{PP}$
Clamping Voltage @ $I_{PP}$	$V_c$
Peak Reverse Working Voltage	$V_{RWM}$
Reverse Leakage Current @ $V_{RWM}$	$I_R$
Breakdown Voltage @ $I_T$	$V_{BR}$
Test Current	$I_T$
Forward Current	$I_F$
Forward Voltage @ $I_F$	$V_F$



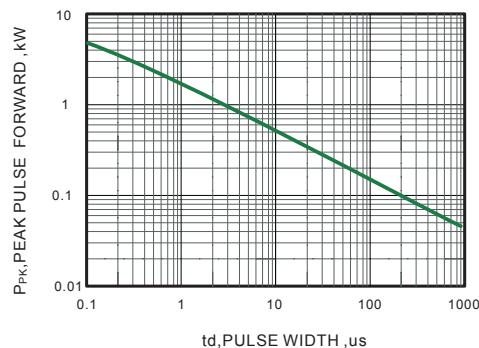
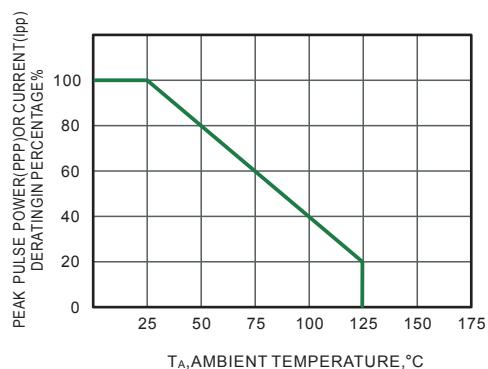
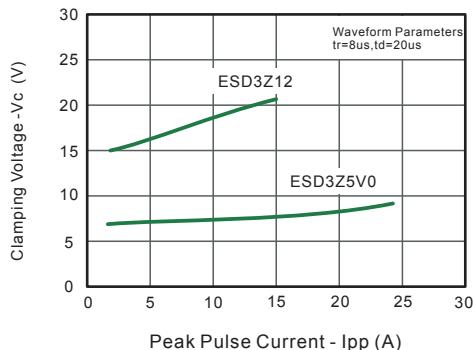
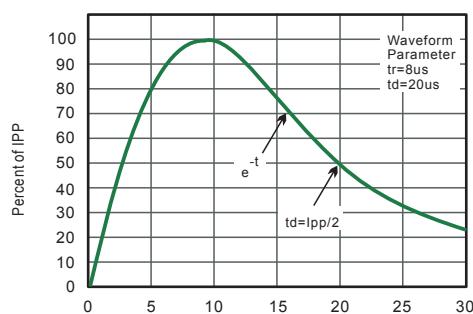
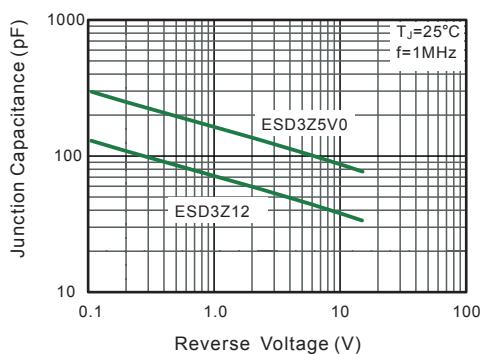
**Absolute Ratings**  
 (Tamb=25°C )

Parameter	Symbol	Value	Unit
Peak Pulse Power(tp=8/20us)	P <sub>PK</sub>	250	W
ESD Voltage(HBM Waveform per IEC 61000-4-2)	V <sub>ESD</sub>	30	kV
Operating Junction Temperature	T <sub>J</sub>	-55 to +125	°C
Storage Temperature	T <sub>STG</sub>	-55 to +150	°C

**Electrical Characteristics**

Ratings at 25 °C ambient temperature unless otherwise specified.

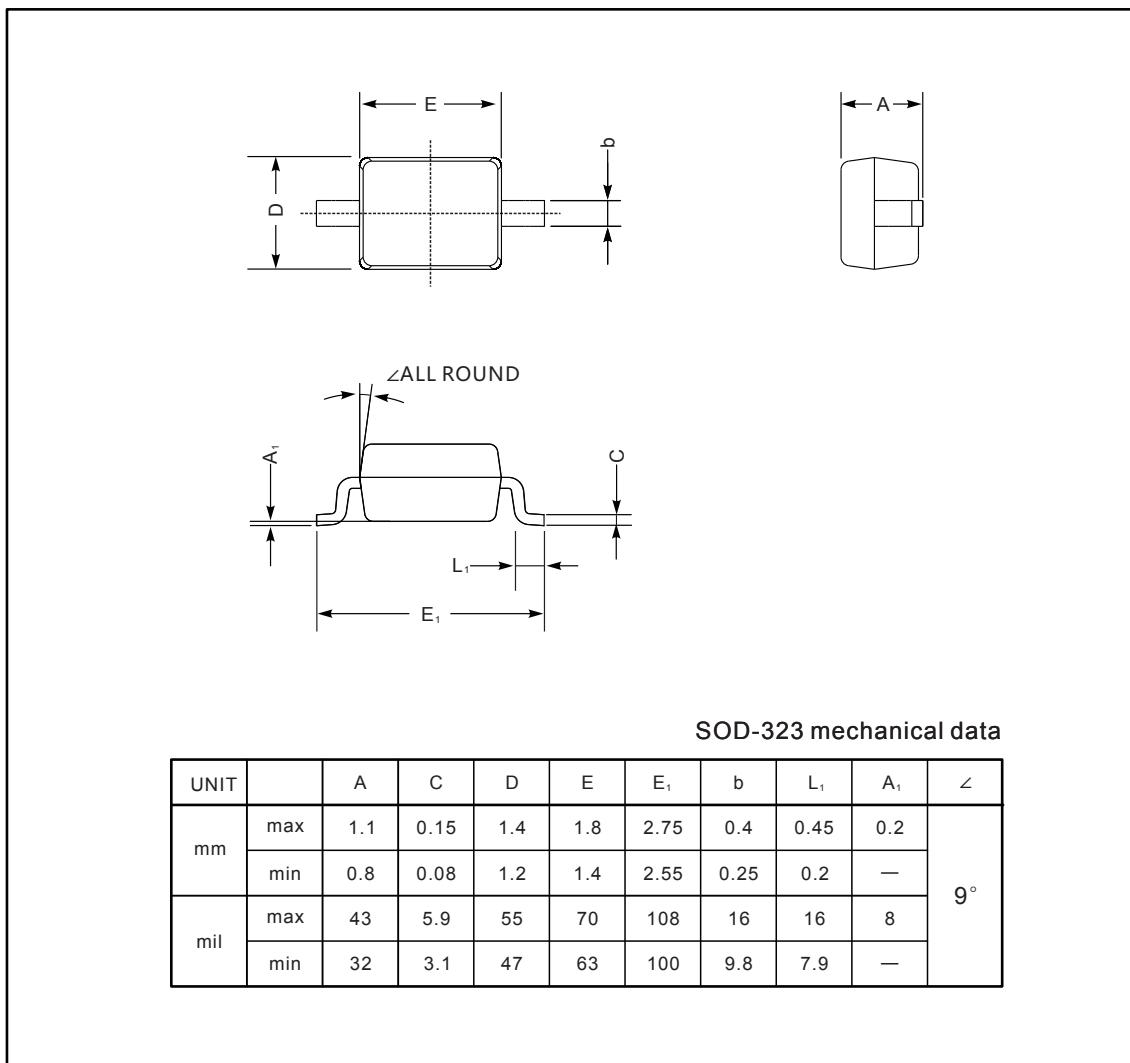
Device	V <sub>RWM</sub> (V)	I <sub>R</sub> (uA) @V <sub>RWM</sub> =5V	V <sub>BR</sub> (V) @IT=1mA	V <sub>C</sub> (V) @IPP=5A tp=8/20us	V <sub>C</sub> (V) @IPP=24A tp=8/20us	I <sub>PP</sub> (A) tp=8/20us	C <sub>J</sub> (pF)
	Max.	Max.	Min.	Typ.	Max.	Max.	Typ.
ESD3Z5V0	5.0	10	6.0	9.8	10.5	24	350
ESD3Z12	12.0	1.0	13.3	19.0	16.5	15	150

**Fig.1 Non-Repetitive Peak Pulse Power vs. Pulse Time****Fig.2 Forward Current Derating Curve****Fig.3 Waveform****Fig.4 Power Derating Curve****Fig.5 Typical Junction Capacitance**

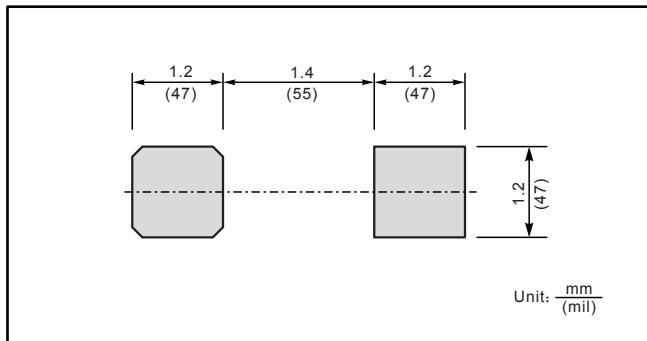
## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



### The recommended mounting pad size



### Marking

Type number	Marking code
ESD3Z5V0	05
ESD3Z12	12